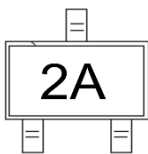


GPB3906 Transistor(PNP)

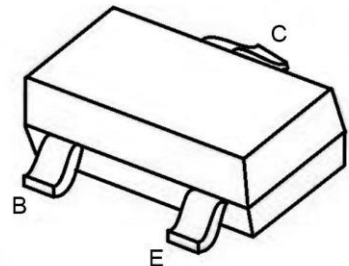
Feature

- Epitaxial Planar Die Construction
- Complementary NPN Type Available(GPB3904)
- Ideal for Medium Power Amplification and Switching

Marking



SOT-23



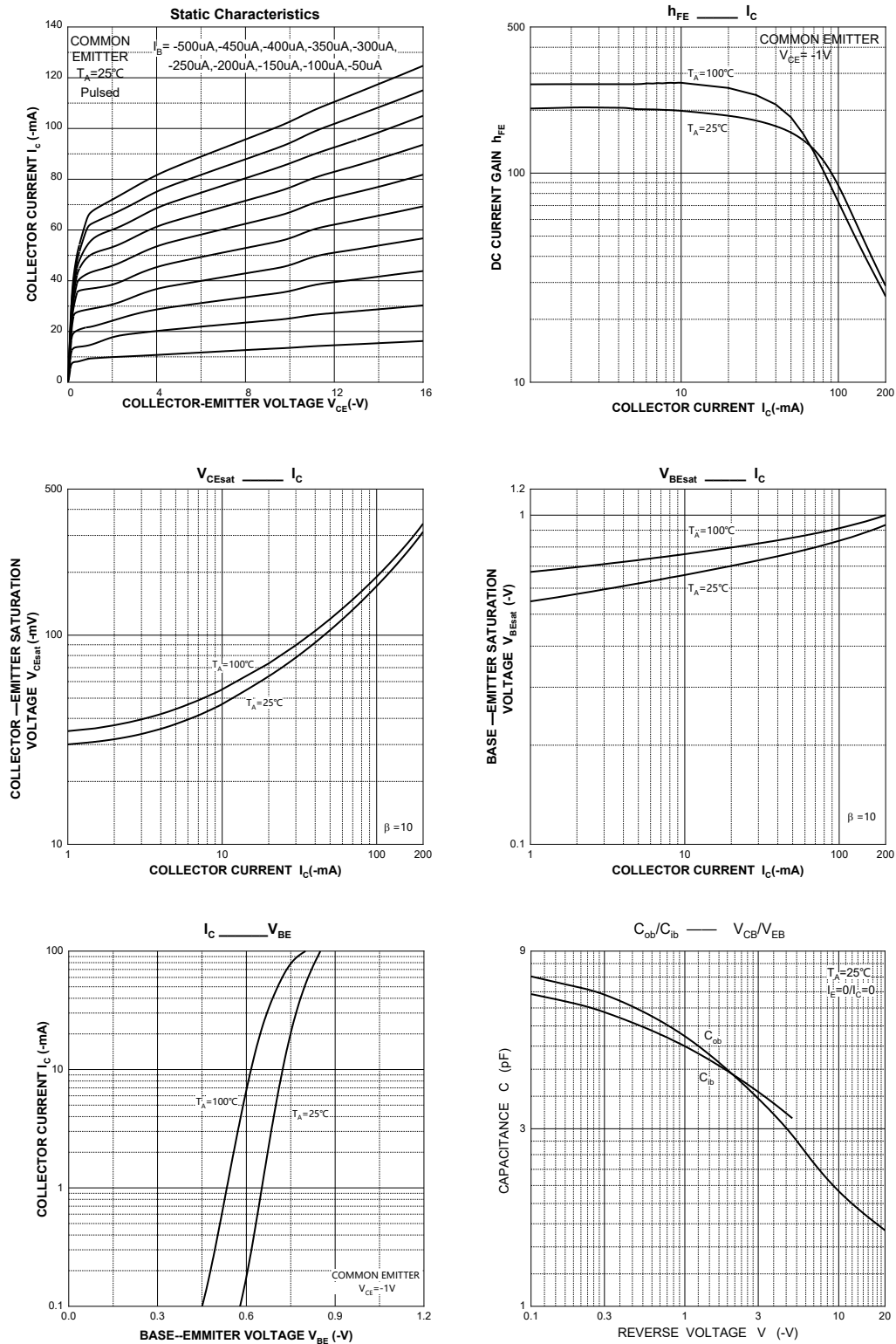
MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

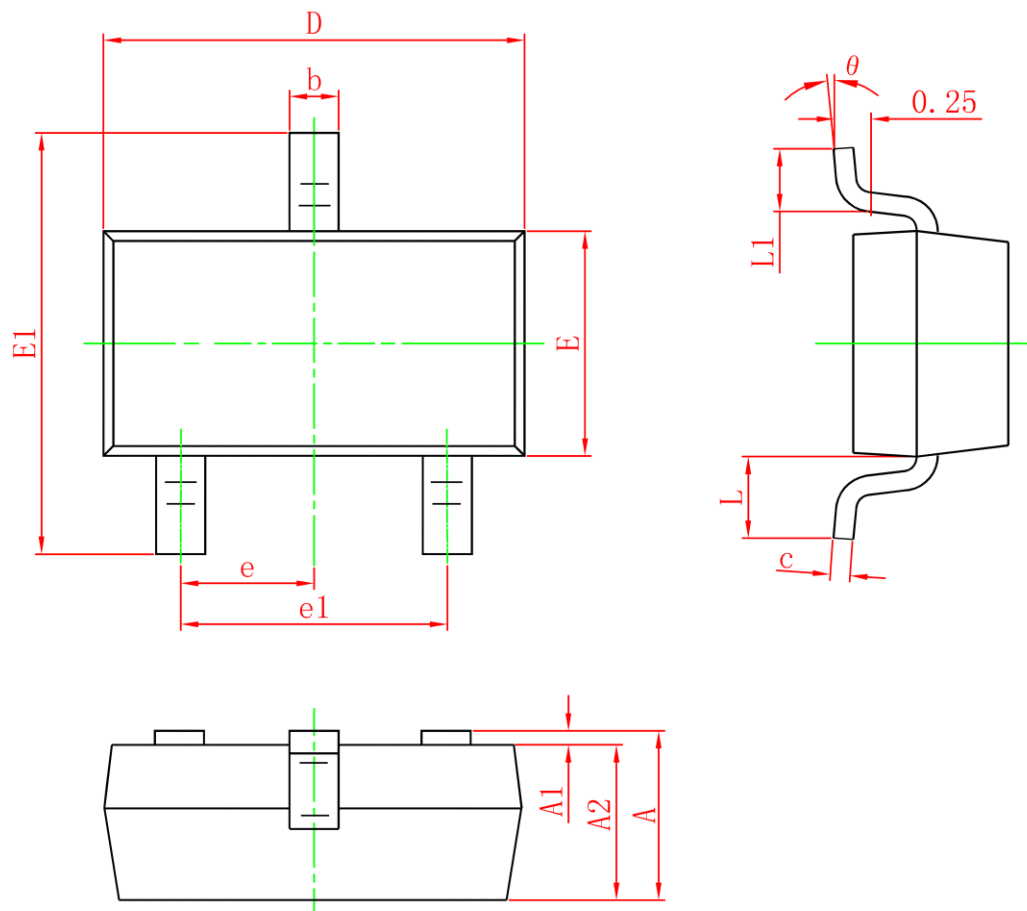
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	-40	V
Collector-Emitter Voltage	V_{CE0}	-40	V
Emitter-Base Voltage	V_{EB0}	-5	V
Collector Current -Continuous	I_C	-0.2	A
Power Dissipation	P_d	0.2	W
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS(T_A=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Max	Unit
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C =-10μA, I _E =0	-40		V
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =-1mA, I _B =0	-40		V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E =-10μA, I _C =0	-5		V
Collector Cut-Off Current	I _{CBO}	V _{CB} =-40V, I _E =0		-100	nA
Collector Cut-Off Current	I _{CEX}	V _{CE} =-30V, V _{EB(OFF)} =-3V		-50	nA
Base Cut-Off Current	I _{EBO}	V _{EB} =-5V, I _C =0		-100	nA
DC Current Gain	h _{FE1}	V _{CE} =-1V, I _C =-10mA	100	300	
	h _{FE2}	V _{CE} =-1V, I _C =-50mA	60		
	h _{FE3}	V _{CE} =-2V, I _C =-100mA	30		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =-50mA, I _B = -5mA		-0.3	V
Base-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-50mA, I _B = -5mA		-0.95	V
Transition Frequency	f _T	V _{CE} = -20V, I _C =-10mA, f =100MHz	300		MHZ
Delay Time	t _d	V _{CC} =-3.0V, I _C = -10mA,		35	ns
Rise Time	t _r	V _{BE(off)} = 0.5V, I _{B1} = I _{B2} = -1.0mA		35	ns
Storage Time	t _s	V _{CC} = -3.0V, I _C = -10mA,		225	ns
Fall Time	t _f	I _{B1} = I _{B2} = -1.0mA		75	ns

Typical Characteristics



SOT-23 Package Information


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0	0.100	0	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.150	1.500	0.045	0.059
E1	2.250	2.650	0.089	0.104
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Attention:

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.